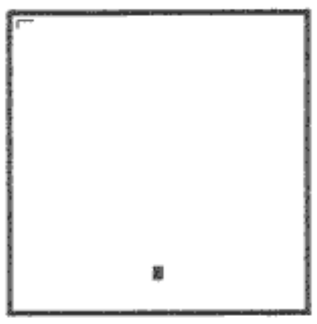
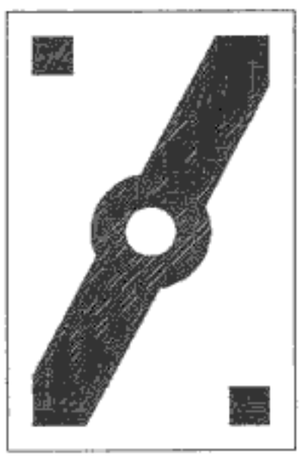
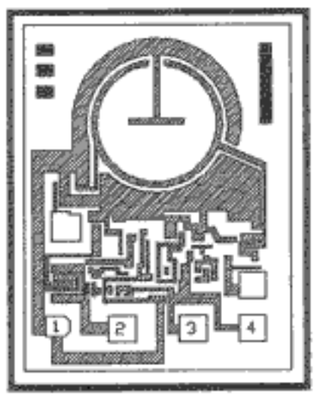
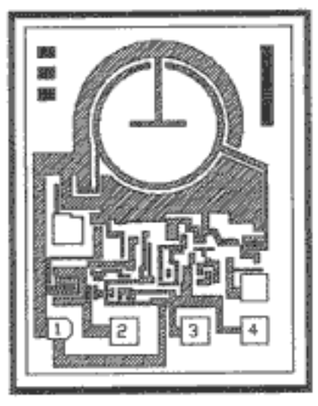
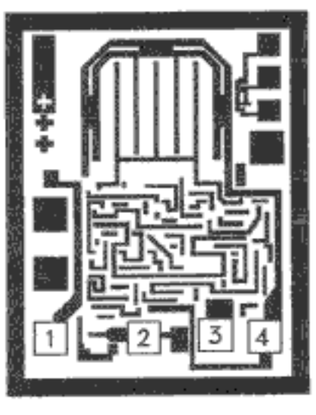
Chip Topography		General Description	Typical Application	Typical Data Parameters	Chip Size (Mils)	Note
	FNX1035	A silicon PIN photodiode chip with high speed and efficiency	· Fiber Optic Link · Digital Interfacing · Linear Interfacing	· Photo area 20 mils Dia · BV_R=50V · R=0.5A/W · C_J=6.0pF · t_r, t_f=3.0ns	35X35	1
	FNX1059	A silicon PIN photodiode chip with large photo area and high efficiency	· Fiber Optic Link · Digital Interfacing · Linear Interfacing	· Photo area 95X95 mils · BV_R=50V · R=0.5A/W · C_J=65pF · t_r, t_f=50ns	99X99	1
	FNX1060	A PIN photodiode chip with very high speed and low leakage current	· Fiber Optic Link · Digital interfacing · Linear interfacing	· Photo area 5 mils Dia · BV_R=50V · R=0.5A/W · C_J=1.0pF · t_r, t_f=1.0ns	16X24	1
	FNX1062	A high speed photo logic chip with an open collector output	· Optoisolators · Digital Interfacing	· Vcc=5.5V · Vo=5.5V · Icc=8mA · Io=13mA · t_{PHL}=55ns · t_{PLH}=55ns	40X50	1
	FNX1063	A high speed photo logic chip with a tri-state output	· Optoisolators · Digital Interfacing	· Vcc=5.5V · Vo=5.5V · Icc=8mA · Io=13mA · t_{PHL}, t_{PLH}=55ns · V_{EH}=2.0V · V_{EL}=0.8V	40X50	1
	FNX1068	A high speed photo logic chip with an open collector output	· Optoisolators · Digital Interfacing	· Vcc=5.5V · Vo=5.5V · Icc=10mA · Io=13mA · t_{PHL}, t_{PLH}=55ns	42X54	1